

Electron Quasiparticles Drive the Superconductor-to-Insulator Transition in Homogeneously Disordered Thin Films

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Transport data on Bi, MoGe, and PbBi/Ge homogeneously-disordered thin films demonstrate that the critical resistivity, R_c , at the nominal insulator-superconductor transition is linearly proportional to the normal sheet resistance, R_N . In addition, the critical magnetic field scales linearly with the superconducting energy gap and is well-approximated by H_{c2} . Because R_N is determined at high temperatures and H_{c2} is the pair-breaking field, the two immediate consequences are: 1) electron-quasiparticles populate the insulating side of the transition and 2) standard phase-only models are incapable of describing the destruction of the superconducting state. As gapless electronic excitations populate the insulating state, the universality class is no longer the 3D XY model, thereby relaxing the constraints that this model imposes on the critical exponents as well as on the critical resistance, namely $R_c \equiv R_Q = h/4e^2$. The lack of a unique critical resistance in homogeneously disordered films can be understood in this context. In light of the recent experiments which observe an intervening metallic state separating the insulator from the superconductor in homogeneously disordered MoGe thin films, we argue that the two transitions that accompany the destruction of superconductivity are 1) superconductor to Bose metal in which phase coherence is lost and 2) Bose metal to localized electron insulator via pair-breaking.

In an issue honouring the work of Michael Pollak, certain topics such as the Coulomb gap and the interplay between disorder and long-range Coulomb interactions naturally come to mind. Nonetheless, we would like to focus on the insulator-superconductor transition in homogeneously disordered thin films. The impetus for this work is the recent observation (Mason and Kapitulnik 1999, Mason and Kapitulnik 2000) in homogeneously disordered thin films of MoGe that two phase transitions are encountered in the magnetic field-tuned transformation of the superconducting phase into an insulator. We argue here that the two transitions correspond to superconductor to Bose metal in which Cooper pairs lack phase coherence and Bose metal to localized electron insulator as illustrated in the global phase diagram in Fig. (1). The latter interpretation is consistent with the extensive work of Dynes, Valles and co-workers, (Dynes, Garno and Rowell 1978, Dynes *et al.* 1994, Barber *et al.* 1994, Valles, Dynes and Garno 1992, Merchant *et al.* 2001, Hsu, Chervenak and Valles 1995, Chervenak and Valles 2000, Chervenak and Valles 1999, Valles *et al.* 2000, Hsu 1995, Chervenak 1998, Kouh 1999) who have argued tirelessly that the insulator-superconductor transition in homogeneously disordered films is driven by amplitude fluctuations or equivalently pair-breaking. While it comes as no surprise that Cooper pairs break apart for sufficiently strong disorder or magnetic fields, it is not widely accepted that this state of affairs obtains generically at the nominal superconductor-insulator transition in homogeneously disordered thin films. That the transport and tunneling data lead necessarily to this conclusion

and that loss of phase coherence leads to a Bose metal phase (rather than a Cooper pair insulator) are the two key results of this work. As Michael Pollak's work has been motivated primarily by experiments on disordered 2D systems, insulator-superconductor transitions (IST) in disordered thin films certainly intersect his work.

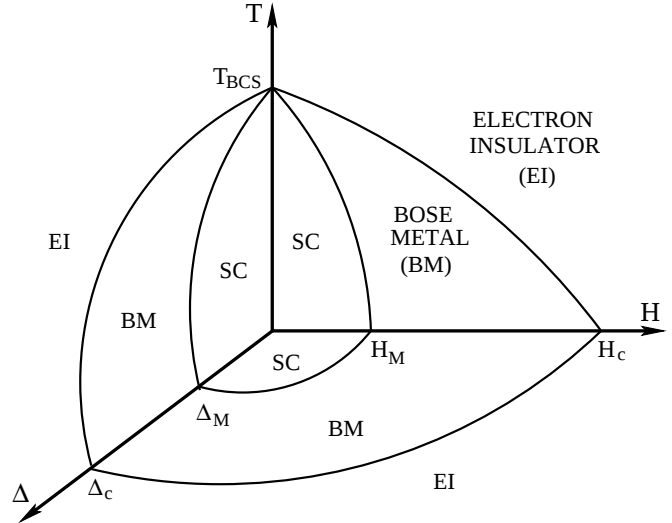


FIG. 1. Global phase diagram for destruction of superconductivity in disordered thin films. At Δ_M and H_M , phase coherence is lost giving rise to a Bose metal phase in which the Cooper pair amplitude remains intact. The pair amplitude vanishes at the upper field H_c and the disorder Δ_c yielding a localized electron insulator.

From the earliest experiments (Dynes, Garno and Rowell 1978, Dynes *et al.* 1994, Barber *et al.* 1994, Valles, Dynes and Garno 1992, Merchant *et al.* 2001, Hsu, Chervenak and Valles 1995, Chervenak and Valles 2000, Chervenak and Valles 1999, Valles *et al.* 2000, Hsu 1995, Hebard and Paalanen 1990, Liu and Goldman 1994, Jaeger *et al.* 1989, Yazdani and Kapitulnik 1995, Goldman and Markovic 1998) on superconducting thin metal alloy films, a simple picture emerged for the magnetic-field or disorder-tuned transition to the insulating state. Namely, the transition is continuous with a well-defined critical field, H_c , below which superconductivity occurs and above which an insulator obtains. At the critical field (or the critical film thickness), the resistivity is independent of temperature.

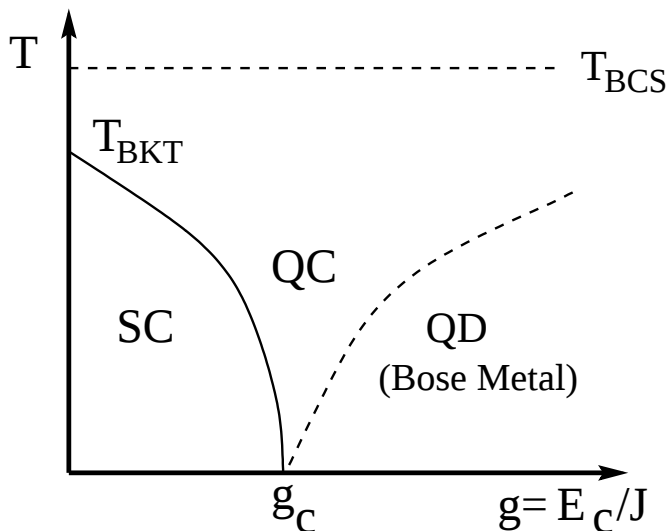


FIG. 2. Phase diagram for an array of Josephson junctions as a function of temperature and the quantum fluctuations, g . For Josephson-junction arrays, g is given by the ratio of the charging energy, E_c , to the Josephson coupling, J . T_{BKT} is the Berezinskii-Kosterlitz-Thouless temperature at which phase coherence obtains. g_c defines the critical value of the phase disorder to destroy the superconducting phase. QC refers to the quantum critical regime in which the inverse correlation length is linear in the temperature. In the quantum disordered regime, QD, a gap appears to all excitations. Phase coherence is absent in this regime. Although this phase is gapped, the dc conductivity remains finite as shown by Dalidovich and Phillips (2000). T_{BCS} defines the mean-field temperature at which the pair amplitude first becomes non-zero.

While phase or pair amplitude fluctuations both destroy superconductivity, the dominant model that was used to explain all of the original experiments on the IST was the phase-only 3D XY model or equivalently the charging model for a Josephson junction array (JJA) (Fisher 1990, Fisher, Grinstein and Girvin 1990, Schakel 2000). Superconducting islands with charging energy E_C linked together by a Josephson pair current, J , constitute the

JJA model. Such a model is expected to apply to any system, granular or otherwise, in which Cooper pair formation and phase coherence occur at distinct energy scales. As illustrated in Fig. (2), such a model possesses a zero-temperature quantum critical point driven solely by fluctuations of the quantum mechanical phase of the order parameter. On the superconducting side of the transition, Cooper pairs form a phase-coherent state in which the resistivity vanishes. On the insulating side, phase coherence is lost and all excitations become gapped. The energy scale for the gap is set by the inverse correlation length. The excitations are purely bosonic, however, as the pair-amplitude is assumed to remain frozen below some mean-field temperature, T_{BCS} . Consequently, electron-like quasiparticles arising from pair amplitude fluctuations are strictly absent from phase-only models. Close to the finite T_c line in Fig. (2), the elementary excitations correspond to vortex-antivortex pairs. Such excitations remain bound below T_c but unbind above. As a result of the inherent duality between Cooper pairs and vortices, the superconducting state can be thought of as a Cooper pair condensate with localized vortices whereas in the quantum-disordered regime, vortices condense but Cooper pairs remain localized.

In a perpendicular magnetic field, vortices of only one vorticity are possible in the superconducting phase. Such vortices interact logarithmically resulting in the stabilization of an Abrikosov vortex lattice. Finite randomness, however, disrupts the lattice leading to glassy ordering. Thus, at sufficiently weak magnetic fields, vortices are localized by both logarithmic Coulomb repulsions and disorder, implying that superconductivity is preserved at $T = 0$. At low temperatures and non-zero magnetic fields, an exponentially small resistivity is expected on the superconducting side as a result of thermally assisted quantum tunneling of vortices. In fact, it is the logarithmic Coulomb interaction between vortices in the presence of disorder that conspires to yield the Mott variable-range hopping form for the resistivity $R(T) \propto \exp -C|\ln T|/T$ (Efros 1976). Experimentally, however, a leveling (Mason and Kapitulnik 1999, Mason and Kapitulnik 2000, Ephron *et al.* 1996, Geerligs *et al.* 1989) of the resistivity rather than an exponential attenuation has been observed in finite field. The saturation value of the resistivity is strongly dependent on the magnetic field and implies that a metallic phase intervenes between the superconductor and the eventual insulator at H_c . More recent experiments (Mason and Kapitulnik 2000) have shown that below a lower value of the magnetic field, H_M , the resistivity does in fact vanish. For the MoGe films, $H_M = .18T$ whereas $H_c \approx 2.5T$ indicating that the two transitions are driven by fundamentally different physics. The emergence of an intervening metallic phase is not restricted only to the magnetic field-tuned problem. In fact, in the disorder-tuned transition, the resistivity has also been observed (Jaeger *et al.* 1989) to

level at low temperatures for weak to intermediate values of the disorder. The saturation value of the resistivity ranges from $.001k\Omega$ to $100k\Omega$. Hence, the metallic phase is robust.

Within the standard dirty boson picture in which bosons exist on both sides of the transition, two permissible values for the resistivity are anticipated: 1) zero (superconductor) or 2) infinity (insulator). However, we have shown (Dalidovich and Phillips 2000) recently that the anticipated insulating state is actually a metal (see Fig. (2)) with a universal dc conductivity given by $(2/\pi)4e^2/h$. While this result is rooted in the noncommutativity (Damle and Sachdev 1997) of the temperature and frequency tending to zero limits of the conductivity, it has a simple physical interpretation. In the quantum-disordered regime, the population of bosons is exponentially suppressed; however, so is the scattering rate between bosons. But because the conductivity is a product of the density and the scattering time, the exponentials cancel, giving rise to a finite conductivity at $T = 0$. Hence, the observation of a metallic state is not entirely inconsistent with phase-only models as depicted in Fig. (2). In fact, our work establishes that the Bose metal is a generic feature of phase-only models. However, the occurrence of two phase transitions in MoGe (Mason and Kapitulnik 1999, Mason and Kapitulnik 2000) is inconsistent with the phase-only model which possesses only a single critical point signaling the termination of phase coherence. Clearly, both transitions cannot be caused by loss of phase coherence. In addition, experimentally, resistivities at criticality ranging from $0.1R_Q$ to $3R_Q$ have been observed in homogeneously disordered films (Liu and Goldman 1994), with $R_Q = h/4e^2$. At criticality, Cooper pairs on the brink of forming a phase coherent state are expected (Fisher 1990, Fisher, Grinstein and Girvin 1990) to diffuse with the quantum of conductance $\sigma_Q = 4e^2/h$ for charge $2e$ bosons. Hence, such deviations from σ_Q and the observation of two transitions suggest that physics beyond phase-only models might be relevant for homogeneously disordered films.

Based on an analysis of the transport experiments (Barber *et al.* 1994, Valles, Dynes and Garno 1992, Hsu, Chervenak and Valles 1995, Yazdani and Kapitulnik 1995, Goldman and Markovic 1998) we suggest that the transition occurring at H_c in MoGe as well as the traditionally-studied IST in homogeneously disordered thin films involves an insulator populated with electron-like quasiparticles as originally argued by Dynes, Valles, and co-workers (Dynes, Garno and Rowell 1978, Dynes *et al.* 1994, Barber *et al.* 1994, Valles, Dynes and Garno 1992, Merchant *et al.* 2001, Hsu, Chervenak and Valles 1995, Chervenak and Valles 2000, Chervenak and Valles 1999, Valles *et al.* 2000, Hsu 1995). A transition driven by Cooper pair breaking lies outside the 3D XY universality class and hence is not constrained to exhibit the unique value of $h/4e^2$ at criticality.

For granular films, phase-only models appear to be adequate primarily because $R_c \approx h/4e^2$ at criticality and the single-particle energy gap (Barber *et al.* 1994) remains finite and unattenuated from the bulk superconducting value on the insulating side of the transition. We propose that measurements of the superfluid density at both transitions observed recently in MoGe will ultimately determine which is of the Berezinskii-Kosterlitz-Thouless (Berezinskii 1971, Kosterlitz and Thouless 1973) form.

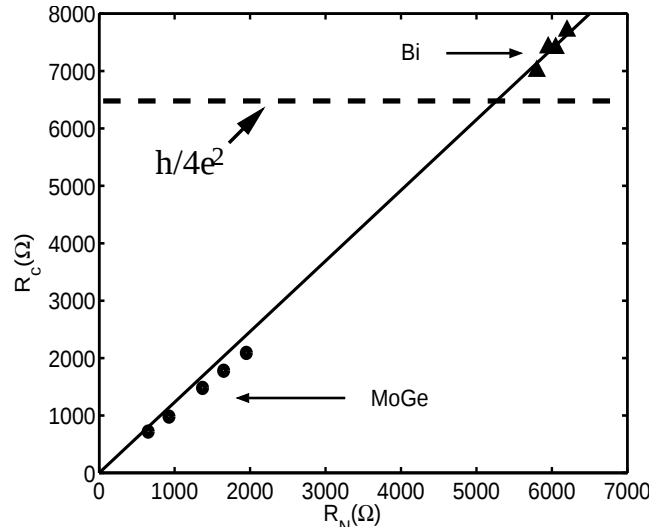


FIG. 3. Critical resistance, R_c as a function of the normal state resistance, R_N for Bi (Goldman and Markovic 1998) and MoGe (Yazdani and Kapitulnik 1995) samples. In both Bi and MoGe, an applied magnetic field tunes the transition. The lack of a universal value at the transition and the correlation of R_c with R_N is an indication that the transition to the insulating state has electron-like quasiparticles, indicative of the high temperature normal state. The dashed line indicates the predicted value of the critical resistance for charge $2e$ bosons of the phase only model. This value is seen in granular films but clearly not in homogeneously disordered films including InO_x (Hebard and Paalanen 1990).

To support our central claim that the time-honored IST in homogeneously disordered films is accompanied by a proliferation of electron-like quasiparticles, we compare the value of the resistivity at criticality with the resistivity in the normal state of the films. Shown in Fig. (3) is such a comparison for Bi and MoGe thin films. The normal state resistance, R_N , was extracted (Goldman and Markovic 1998, Yazdani and Kapitulnik 1995) from transport measurements at $T > T_{BCS}$. Hence, only electron-like excitations abound in this temperature range. The critical resistance, R_c , is extracted much below T_{BCS} and represents the limiting value of the resistance at the single crossing point of $R(T)$ vs tuning parameter as $T \rightarrow 0$. In both the Bi and MoGe thin films, an applied magnetic field induces the IST. As is evident from the data shown, for both Bi and MoGe, $R_c \propto R_N$. Unless a transition to the normal ground state occurs

at R_c , there is no reason to expect that $R_c \propto R_N$. We conclude then that because R_N is associated with high temperature physics in which no Cooper pairs exist, the fact that $R_c \propto R_N$ signifies that the insulating state must have electron-like quasiparticles in homogeneously disordered thin films. Further, in all cases, R_c slightly exceeds R_N and ranges between 900Ω and 8000Ω . In contrast, granular films (Hebard and Paalanen 1990) display a critical resistance that is in accordance with the prediction of phase-only models as the dashed line in Fig. (3) attests. Consequently, the non-universal value of R_c in homogeneously disordered films implies that physics beyond phase-only models must be at work.

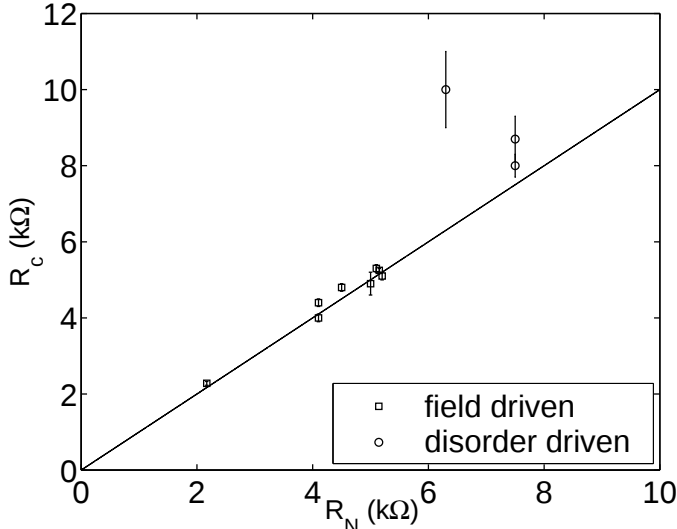


FIG. 4. Critical resistance, R_c as a function of the normal state resistance, R_N for Bi/Sb (disorder-tuned) (Chervenak and Valles 1999, Chervenak 1998, Kouh 1999) and PbBi/Ge and Bi/Sb (field-tuned) (Hsu, Chervenak and Valles 1995, Chervenak 1998, Hsu 1995) samples. The linear relationship between R_c and R_N is consistent with the Bi and MoGe data in Fig. (2). This suggests that the IST in homogeneous films is driven the high temperature physics of the normal state.

Further corroborating data on the homogeneously disordered Bi/Sb and PbBi/Ge films are shown in Fig. (4). The error bars represent the inherent error in extracting R_c . For the disorder-tuned transition, the error bars are naturally larger than in the field-tuned case as a result of the uncertainties in measuring the thickness of the sample. For the field-tuned transition, the correlation between R_c and R_N is striking and systematic. Further, R_c is not well approximated by R_Q . These facts are highly suggestive that the insulating state in PbBi/Ge contains unpaired electrons as in the normal state of the films. However, the data which clinch this scenario are the tunneling measurements which probe the single particle energy gap. The emergence of electronic excitations on the insulating side would imply that the Cooper pair ampli-

tude should vanish at the IST. Within such a scenario, the critical magnetic field is expected to be equal to H_{c2} and as a consequence should scale linearly with the gap in the single particle spectrum. Data (Hsu 1995) showing clearly that the gap in the single particle spectrum inferred from tunneling scales linearly with the critical field, H_c , are shown in Fig. (5). Such a correspondence is expected within BCS theory (Bardeen, Cooper and Schrieffer 1957), provided that H_c corresponds to H_{c2} . Hence, the linear relationship found here provides direct evidence that amplitude fluctuations drive the transition to the insulating state as has been noted previously by Valles and his co-workers (Hsu, Chervenak and Valles 1995, Valles *et al.* 2000, Hsu 1995). In fact, Valles and co-workers (Hsu, Chervenak and Valles 1995) have determined that at H_c , the density of states at the Fermi energy is 80% of its value in the normal state. Consequently, a large fraction of the sample contains no Cooper pairs. This observation is also consistent with the series of experiments by Dynes and co-workers (Valles, Dynes and Garno 1992), in which the energy gap has been observed to vanish at the nominal critical field, H_c . While the average gap might vanish at the transition, pairs can still exist as a result of fluctuations of the pair amplitude. Consequently, above T_c , Aslamazov-Larkin paraconductivity is anticipated (on the conducting side) and in fact observed experimentally in PbBi/Ge films (Hsu, Chervenak and Valles 1995).

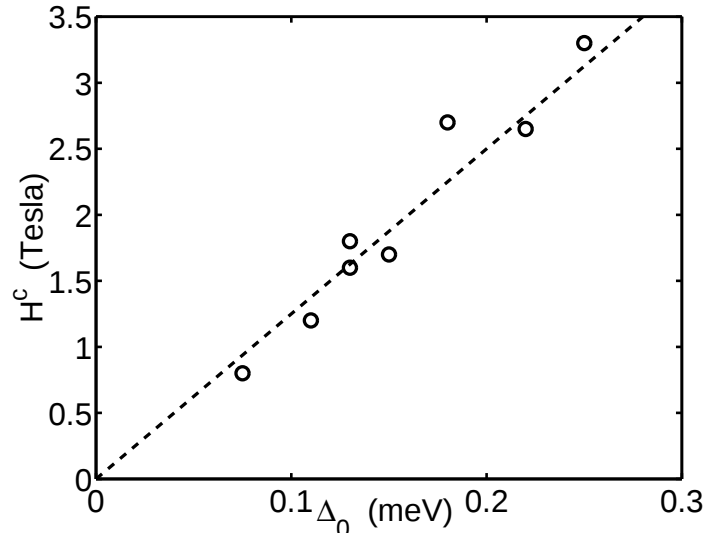


FIG. 5. Critical magnetic field H_c versus the energy gap, Δ_0 for PbBi/Ge films. Redrawn from S.-Y. Hsu's thesis (Hsu 1995)

For the MoGe thin films, Yazdani and Kapitulnik (Yazdani and Kapitulnik 1995) have also noted the surprising correlation between H_c and H_{c2} . In light of this, and the similar trends in other homogeneously disordered films, we conclude that the transition at H_c leads to a prolif-

eration of electronic excitations. We interpret the insulator above H_c as a localized electron insulator rather than a Mott insulator of Cooper pairs. We argue that it is at the lower field, H_M , that phase coherence is lost and a Bose metal phase obtains as has been discussed previously (Dalidovich and Phillips 2000, Das and Doniach 1999). Consequently, we are led to the global phase diagram shown in Fig. (1) for the destruction of superconductivity in homogeneously disordered thin films. The presence of the Bose metal phase (which results directly from finite temperature relaxation between Cooper pairs (Dalidovich and Phillips 2000)) represents direct evidence that the phase and amplitude degrees of freedom are destroyed at different energy scales. In the case of pair breaking, gapless electronic excitations exist on the insulating side of the transition. Consequently, the universality class of the transition is fundamentally different (Fradkin 2001) than in the phase-only model. As the universality class is no longer the 3D XY model, a critical resistance of $R_Q = h/4e^2$ and a correlation length exponent of $\nu = 2/3$ (for the clean system) need no longer hold. This change in universality class could explain the lack of a unique value for the critical resistance in homogeneously disordered thin films and the scatter in the experimental values for the product of the dynamical and correlation length exponents (Liu and Goldman 1994, Seidler, Rosenbaum and Veal 1992, Markovic, Christiansen and Goldman 1998). Progress in including normal electrons into the IST could be made along the lines pursued recently by Feigelman and Larkin (Feigelman and Larkin 1998). Finally, if our argument is correct that phase coherence is lost at H_M , then the superfluid density should exhibit the characteristic drop-off (Berezinskii 1971, Kosterlitz and Thouless 1973) to zero at H_M . Experiments which probe the penetration depth, though extremely difficult on thin films, are essential for these unanswered questions to be laid to rest.

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